

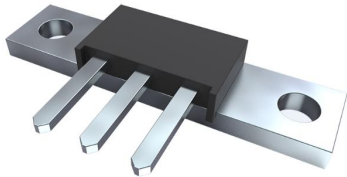
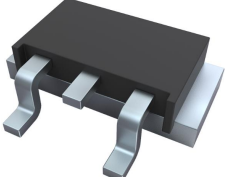
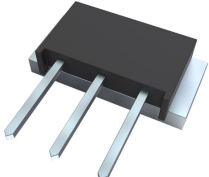
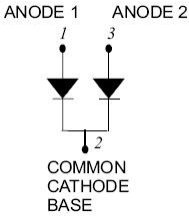
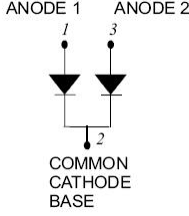
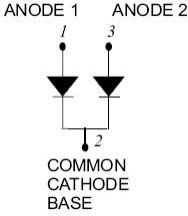
66CNQ200 SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features

- 175°C T_J operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

66CNQ200	66CNQ200SL	66CNQ200SM
		
		
PRM3	PRM3-SL	PRM3-SM

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	V _{RRM}	-	200	V
Working Peak Reverse Voltage	V _{RWM}			
DC Blocking Voltage	V _R			
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _C = 155°C, rectangular wave form	30(Per Leg) 60(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per leg)	I _{FSM}	8.3 ms, half Sine pulse	708	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop (Per leg) *	V _{F1}	@ 30A, Pulse, T _J = 25 °C	0.80	0.92	V
	V _{F2}	@ 30A, Pulse, T _J = 125 °C	0.63	0.72	V
Reverse Current (Per leg) *	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.0002	1.5	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	0.28	21	mA
Junction Capacitance(Per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	750	900	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

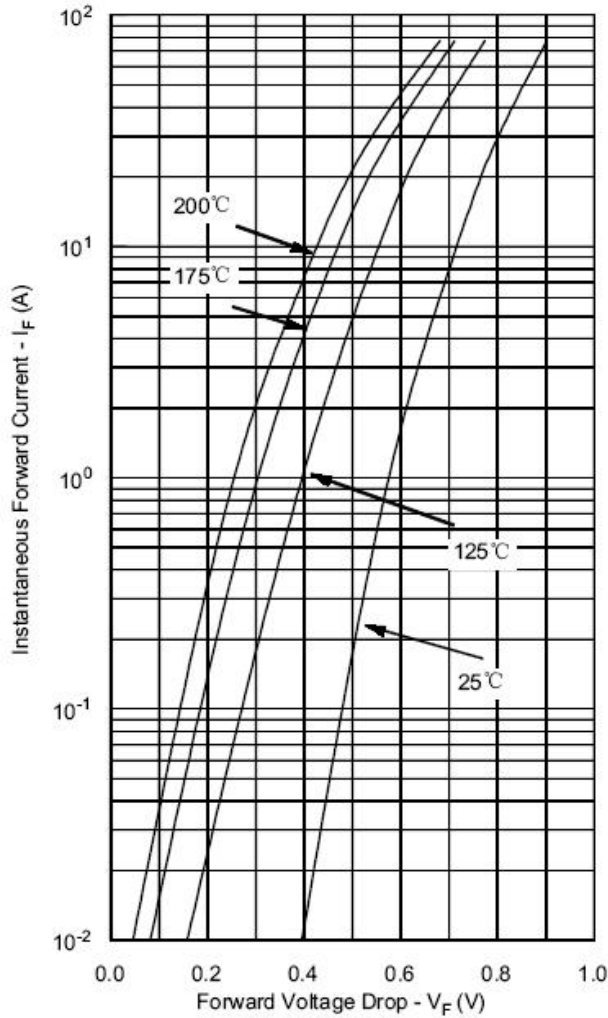
* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

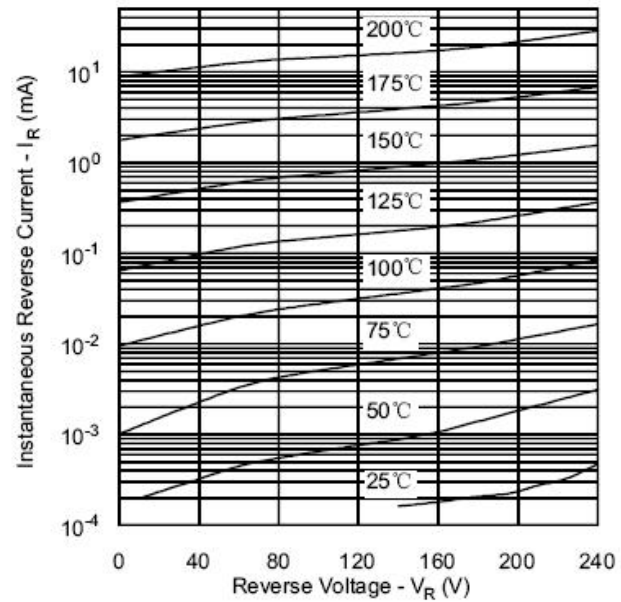
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T _J	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	0.85	°C/W
Typical Thermal Resistance Junction to Case (per package)	R _{θJC}	DC operation	0.42	°C/W
Typical Thermal Resistance, case to Heat Sink	R _{θcs}	Mounting surface, smooth and greased	0.30	°C/W
Mounting Torque	TM	-	40(min)	Kg-cm
			58(max)	
Approximate Weight	wt	-	7.8	g
Case Style	PRM3 PRM3-SL PRM3-SM			

Ratings and Characteristics Curves

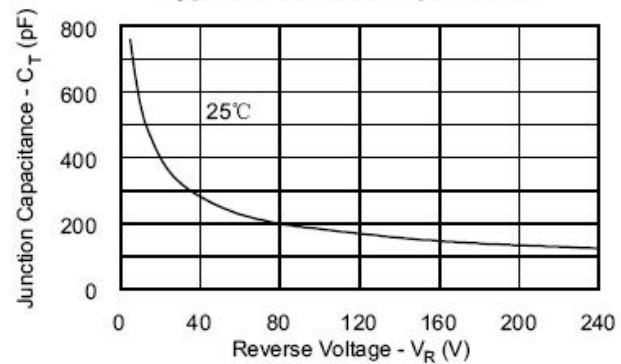
Typical Forward Characteristics



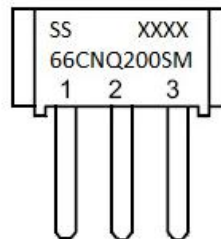
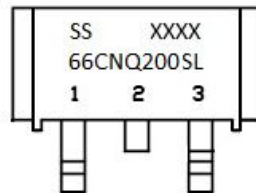
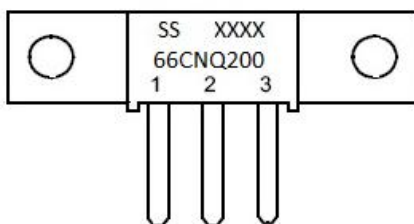
Typical Reverse Characteristics



Typical Junction Capacitance



Marking Diagram



Where XXXX is YYWW

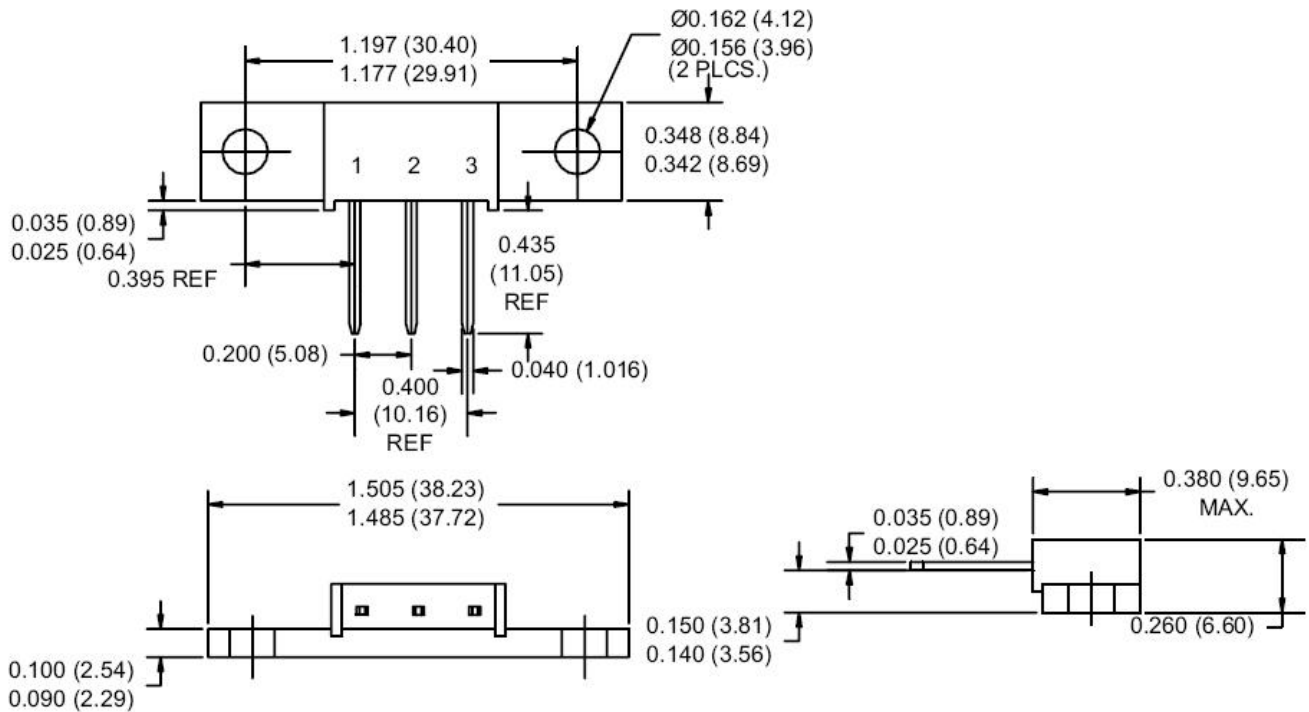
1st row SS YYWWL
2nd row 66CNQ200/SL/SM
3rd row 1 2 3 (pin)
SS = SS
YY = Year
WW = Week

Cautions: Molding resin
Epoxy resin UL:94V-0

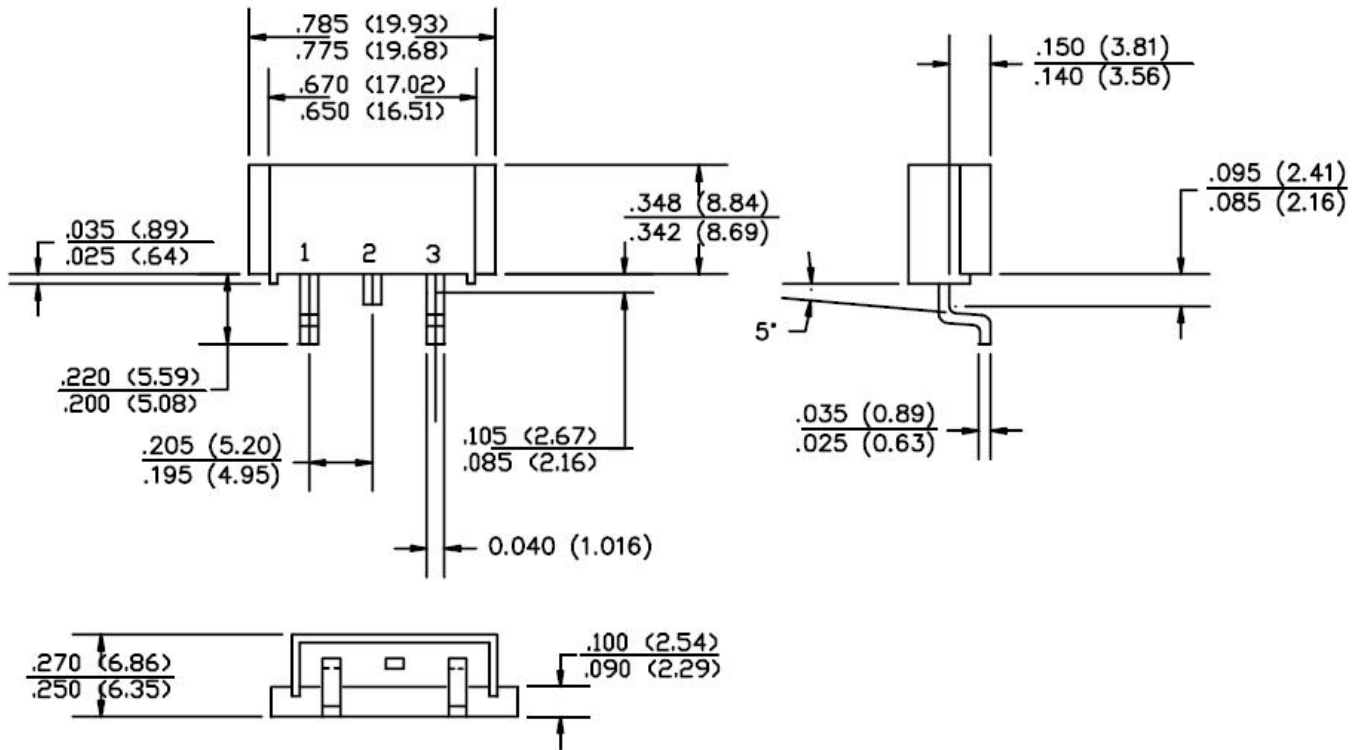
Ordering Information

Device	Package	Terminals finish	Baseplate finish	Shipping
66CNQ200	PRM3	Nickel plated	Nickel plated	48pcs / box
66CNQ200S2	PRM3	Pure Sn dipped (dipped height 6-8mm)	Nickel plated	48pcs / box
66CNQ200SL	PRM3-SL	Pure Sn plated	Pure Sn plated	100pcs / box
66CNQ200SM	PRM3-SM	Nickel plated	Nickel plated	48pcs / box
66CNQ200SMS2	PRM3-SM	Pure Sn dipped (dipped height 6-8mm)	Nickel plated	48pcs / box

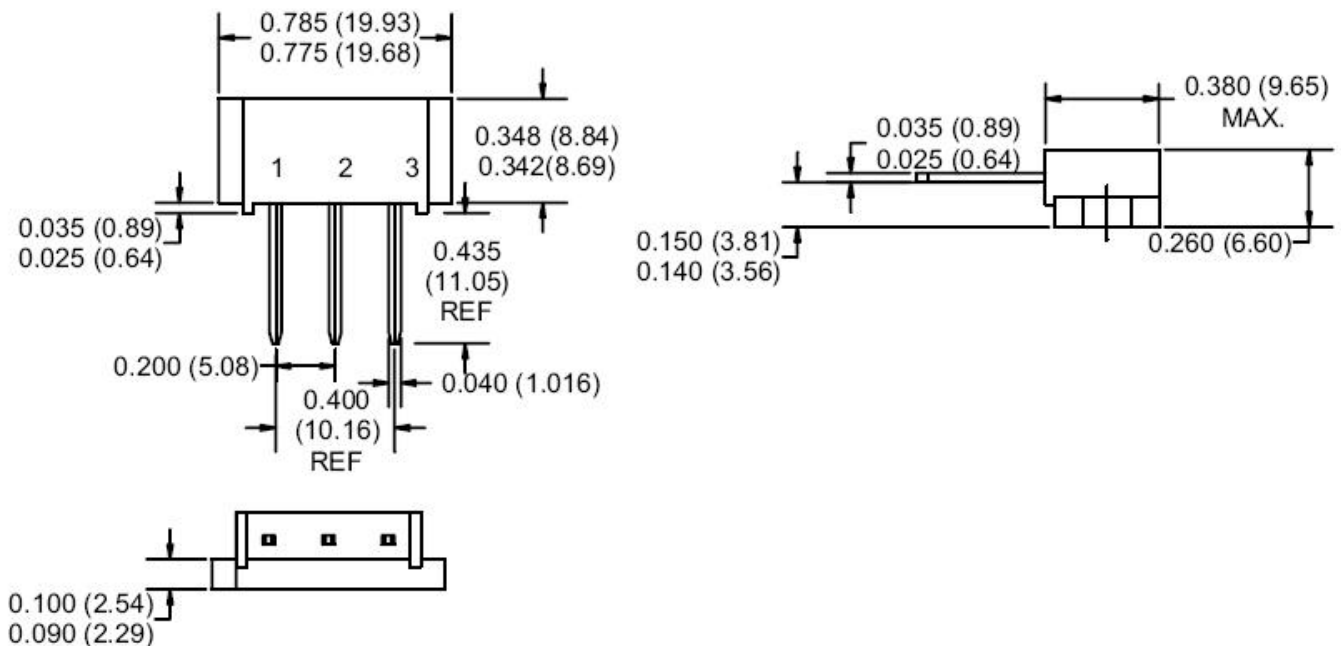
Mechanical Dimensions PRM3 (Inches/Millimeters)



Mechanical Dimensions PRM3-SL (Inches/Millimeters)



Mechanical Dimensions PRM3-SM (Inches/Millimeters)



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